

B²

The process steps shown in Figures 2a-2l are also applicable to other surfaces of different shapes, as stated previously. Figure 2m shows the application to "folded" surfaces having regions with triangular cross-sections. Regions with other cross-sections can also be formed, as well as a combination may be achieved through alternating layers with flat surfaces and folded regions having triangular cross-sections.

IN THE CLAIMS

Please amend the claims as follows:

B³
Sub C³

1. (AMENDED) A stacked-gate flash memory cell having a floating Poly-Si gate with multiply connected surfaces of different shapes comprising:

a semiconductor substrate;

a floating Poly-Si gate with multiply connected surfaces having regions of different cross-sectional shapes;

wherein said cross-sectional shapes are selected from a group consisting of rectangular and triangular shapes;